



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
60V	$8.0 \text{m}\Omega$ @ V _{GS} = 10V	16.5A

Description and Applications

This new generation N-Channel enhancement mode MOSFET is designed to minimize R_{DS(ON)} yet maintain superior switching performance. This device is ideal for use in notebook battery power managements and load switches.

- Motor controls
- DC-DC converters
- Power managements

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications</p>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

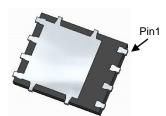
 An automotive-compliant part is available under separate datasheet (DMNH6008SPSQ)

Mechanical Data

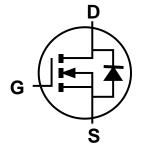
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 [®]
- Weight: 0.097 grams (Approximate)



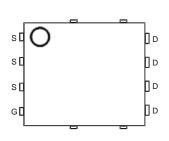
Top View



Bottom View



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

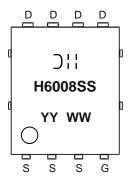
Orderable Part Number	Daakana	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMNH6008SPS-13	PowerDI5060-8	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



D: I = Manufacturer's Marking
H6008SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 24 = 2024)
WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit				
Drain-Source Voltage	VDSS	60	V				
Gate-Source Voltage			Vgss	±20	V		
Continuous Drain Correct (Note C) Von 40V	Steady State	T _A = +25°C T _A = +100°C	I _D	16.5 11.7	А		
Continuous Drain Current (Note 6) Vos = 10V	Steady State	Tc = +25°C Tc = +100°C	I _D	88 63	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	352	Α				
Maximum Continuous Body Diode Forward Current	Is	90	Α				
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			ulsed Source Current (10µs Pulse, Duty Cycle = 1%)		Іѕм	352	Α
Avalanche Current (Note 7) L=0.1mH	lanche Current (Note 7) L=0.1mH		las	62	Α		
Avalanche Energy (Note 7) L=0.1mH	E _{AS}	194	mJ				

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	95	°C/W
Total Power Dissipation (Note 6)		PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	46	°C/W
Thermal Resistance, Junction to Case (Note 6)		R _θ JC	1.6	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

^{6.} Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS			1	μA	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		6.0	8.0	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	Vgs = 0V, Is = 1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	2597	_		V _{DS} = 30V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	437	_	pF		
Reverse Transfer Capacitance	Crss	_	118	_			
Gate Resistance	Rg	_	2.0	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	40.1	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	21.2	_	nC	\/ 20\/ I- 20A	
Gate-Source Charge	Qgs	_	8.3	_	nc	V _{DD} = 30V, I _D = 20A	
Gate-Drain Charge	Qgd	_	11.8	_			
Turn-On Delay Time	tD(ON)	_	5.7	_		$V_{DD} = 30V, V_{GS} = 10V,$ $R_{G} = 1\Omega, I_{D} = 20A$	
Turn-On Rise Time	t _R	_	5.0	_			
Turn-Off Delay Time	tD(OFF)	_	15.6	_	ns		
Turn-Off Fall Time	tF	_	3.3	_			
Reverse-Recovery Time	trr	_	33	_	ns	I- 200 di/dt 4000///-	
Reverse-Recovery Charge	Qrr	_	33		nC	I _F = 20A, di/dt = 100A/μs	

Notes:

^{8.} Short duration pulse test used to minimize self-heating effect.

^{9.} Guaranteed by design. Not subject to product testing.





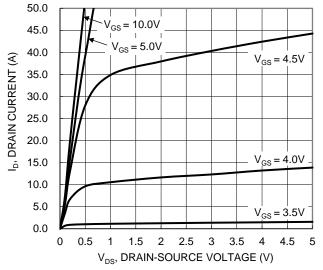


Figure 1. Typical Output Characteristic

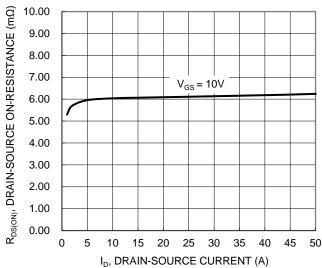


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

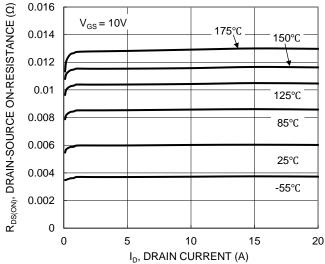


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

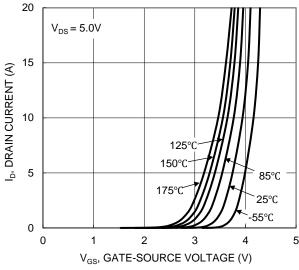


Figure 2. Typical Transfer Characteristic

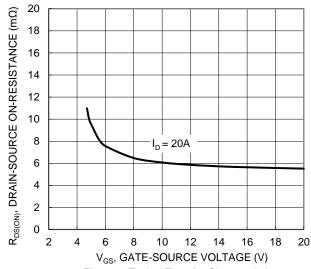


Figure 4. Typical Transfer Characteristic

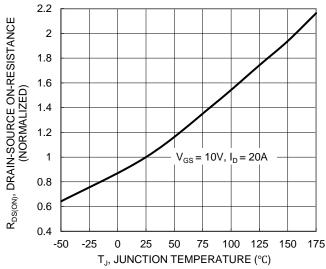


Figure 6. On-Resistance Variation with Temperature



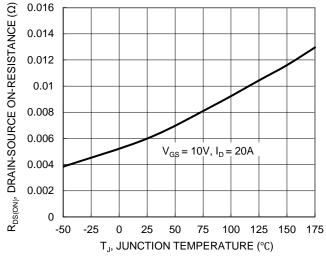


Figure 7. On-Resistance Variation with Temperature

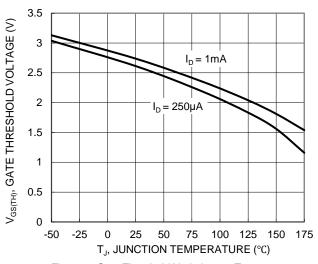


Figure 8. Gate Threshold Variation vs. Temperature

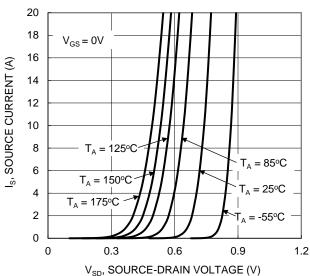
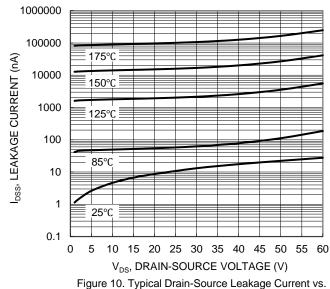


Figure 9. Diode Forward Voltage vs. Current



Voltage

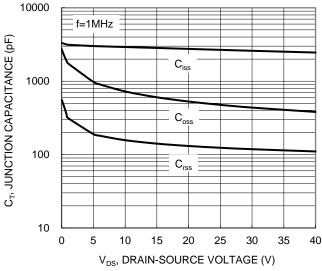


Figure 11. Typical Junction Capacitance

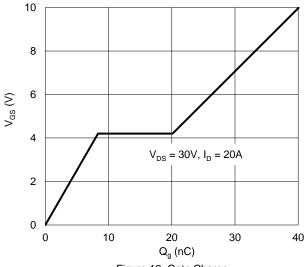
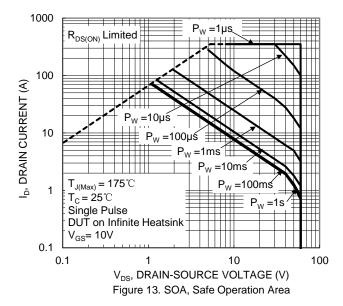


Figure 12. Gate Charge





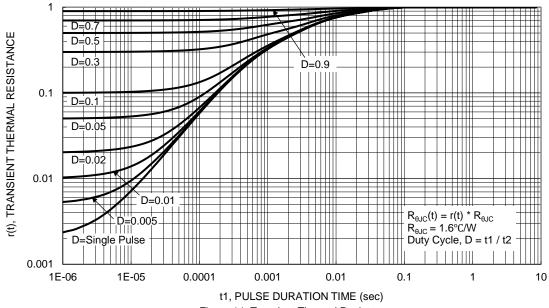


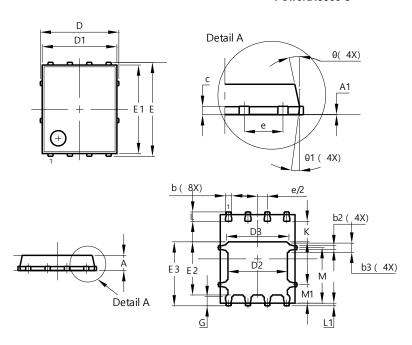
Figure 14. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

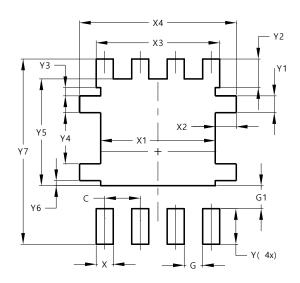


PowerDI5060-8					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	į.	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90 4.30 4.10				
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	_	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)				
С	1.270				
G	0.660				
G1	0.820				
Х	0.610				
X1	4.100				
X2	0.755				
Х3	4.420				
X4	5.610				
Y	1.270				
Y1	0.600				
Y2	1.020				
Y3	0.295				
Y4	1.825				
Y5	3.810				
Y6	0.180				
Y7	6.610				



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